





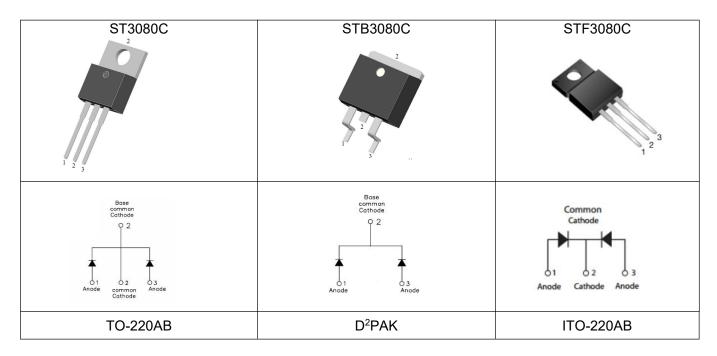
## ST3080C/STB3080C/STF3080C SCHOTTKY RECTIFIER

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Features**

- 150 °C T<sub>J</sub> operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	80	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=116°C(TO-220AB, D2PAK) Tc=82°C(ITO-220AB), In DC	15(Per Leg) 30(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	150	Α

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#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25 °C @ 7.5A, Pulse, T <sub>J</sub> = 25 °C @ 15A, Pulse, T <sub>J</sub> = 25 °C	0.45 0.48 0.57	- - 0.82	V
	V <sub>F2</sub>	@ 5A, Pulse, T <sub>J</sub> = 125 °C @ 7.5A, Pulse, T <sub>J</sub> = 125 °C @ 15A, Pulse, T <sub>J</sub> = 125 °C	0.35 0.40 0.52	- - 0.70	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.02	0.7	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125  ^{\circ}\text{C}$	15	35	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	1040	-	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

#### **Thermal-Mechanical Specifications:**

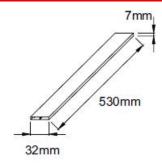
Characteristics	Symbol	ST3080C	STB3080C	STF3080C	Units
Junction Temperature	TJ	-55 to +150		°C	
Storage Temperature	T <sub>stg</sub>	-55 to +150			°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>0</sub> JC	2.8	2.8	5.5	°C/W

## **Tube Specification**

Device	Package	Weight	Shipping
ST3080C	TO-220AB	2.0	50pcs / tube
STB3080C	D <sup>2</sup> PAK	1.85	800pcs / reel
STF3080C	ITO-220AB	2.0	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Tube Specification(TO-220AB/ITO-220AB)**



<sup>•</sup> China - Germany - Korea - Singapore - United States •

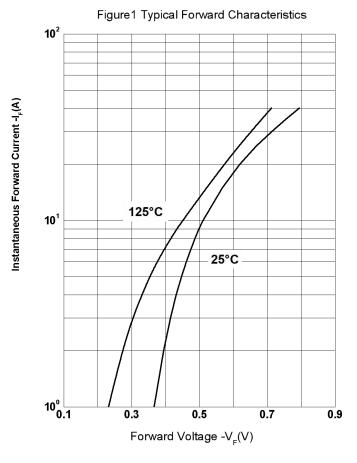
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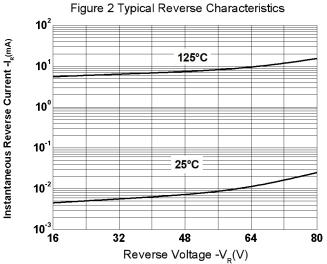


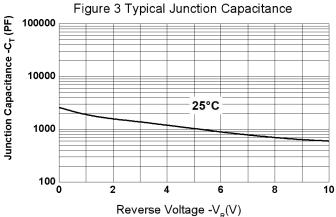




### **Ratings and Characteristics Curves**





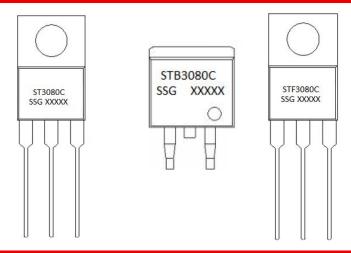








### **Marking Diagram**



#### Where XXXXX is YYWWL

 ST
 = Device Type

 B/F
 = Package type

 30
 = Forward Current (30A)

 80
 = Reverse Voltage (80V)

 C
 = Configuration

 SSG
 = SSG

 YY
 = Year

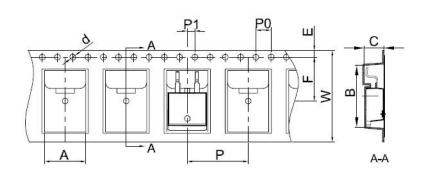
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

### **Carrier Tape Specification D2PAK**



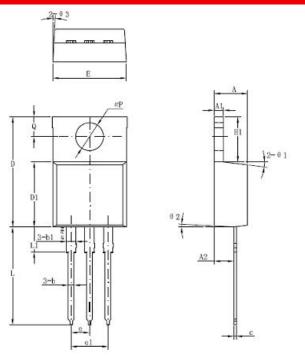
SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	





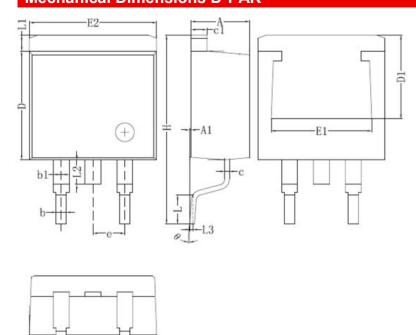


# **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters			
	Min	Typical	Max	
Α	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
Е	9.65	-	10.67	
е	-	2.54	-	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

#### **Mechanical Dimensions D<sup>2</sup>PAK**



Symbol	Dimensions in millimeters		
Symbol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

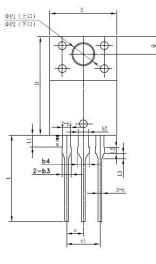
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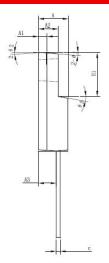






### **Mechanical Dimensions ITO-220AB**







	Dimensions in millimeters			
Symbol	Min.	Typical	Max.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦP1(上口)	3.30	3.50	3.70	
<b>ΦP2</b> (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		







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